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Diodes Incorporated 74LVCE1G04W5-7

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Pin Assignments

NC

1

A 2

GND 3



74LVCE1G04

SINGLE INVERTER GATE

5 Vcc

4 Y

Description

The 74LVCE1G04 is a single inverter gate with a standard totem pole output. The device is designed for operation with a power supply range of 1.4V to 5.5V. The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output preventing damaging current backflow when the device is powered down.

The gate performs the positive Boolean function:

$$Y = \overline{A}$$

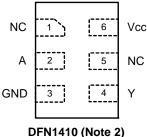
Features

- Extended Supply Voltage Range from 1.4 to 5.5V
- Switching speed characterized for operation at 1.5V
- Offers 30% speed improvement over LVC at 1.8V.
- ± 24mA Output Drive at 3.3V
- CMOS low power consumption
- IOFF Supports Partial-Power-Down Mode Operation
- Input accepts up to 5.5V
- ESD Protection Tested per JESD 22
 Exceeds 200-V Machine Model (A115-A)
 Exceeds 2000-V Human Body Model (A114-A)
- Latch-Up Exceeds 100mA per JESD 78, Class II
- Range of Package Options
- Direct Interface with TTL Levels
- SOT25, SOT353, and DFN1410: Assembled with "Green" Molding Compound (no Br, Sb)
- Lead Free Finish/ RoHS Compliant (Note 1)

(Top View)

SOT25 / SOT353

(Top View)



Applications

- Voltage Level Shifting
- General Purpose Logic
- Wide array of products such as.
 - o PCs, networking, notebooks, netbooks, PDAs
 - o Computer peripherals, hard drives, CD/DVD ROM
 - o TV, DVD, DVR, set top box
 - o Cell Phones, Personal Navigation / GPS
 - o MP3 players ,Cameras, Video Recorders

Notes: 1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied. Please visit our website at http://www.diodes.com/products/lead_free.html.

2. Pin 2 and pin 5 of the DFN1410 package are internally connected.





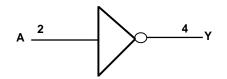
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Pin Descriptions

Pin Name	Description				
NC	No connection				
А	Data Input				
GND	Ground				
Y	Data Output				
Vcc	Supply Voltage				

Logic Diagram



Function Table

Inputs	Output
Α	Y
Н	L
L	Н

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Absolute Maximum Ratings (Note 3)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD MM	Machine Model ESD Protection	200	V
V _{CC}	Supply Voltage Range	-0.5 to 6.5	V
Vi	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage applied to output in high impedance or I _{OFF} state	-0.5 to 6.5	V
Vo	Voltage applied to output in high or low state	-0.3 to V _{CC} +0.5	V
I _{IK}	Input Clamp Current V _I <0	-50	mA
Ι _{ΟΚ}	Output Clamp Current	-50	mA
Ι _Ο	Continuous output current	±50	mA
	Continuous current through Vdd or GND	±100	mA
TJ	Operating Junction Temperature	-40 to 150	°C
T _{STG}	Storage Temperature	-65 to 150	°C

Note: 3. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.





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Recommended Operating Conditions (Note 4)

Symbol		Parameter	Min	Max	Unit
		Operating	1.4	5.5	V
V_{CC}	Operating Voltage	Data retention only	1.2		V
		$V_{CC} = 1.4 \text{ V to } 1.95 \text{ V}$	0.65 X V _{CC}		
M	Link lovel longet \/eltere	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7		V
V _{IH}	High-level Input Voltage	$V_{CC} = 3 V \text{ to } 3.6 V$	2		V
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	0.7 X V _{CC}		
		$V_{CC} = 1.4 \text{ V to } 1.95 \text{ V}$		0.35 X V _{CC}	
V		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7	
V _{IL}	Low-level input voltage	$V_{CC} = 3 V \text{ to } 3.6 V$		0.8	V
	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		0.3 X V _{CC}		
VI	Input Voltage	·	0	5.5	V
Vo	Output Voltage		0	V _{CC}	V
		Vcc=1.4 V		-3	
		V _{CC} = 1.65 V		-4	
		V _{CC} = 2.3 V		-8	
I _{OH}	High-level output current			-16	mA
		$V_{CC} = 3 V$		-24	
		V _{CC} = 4.5 V		-32	
		Vcc=1.4 V		3	
		V _{CC} = 1.65 V		4	
		V _{CC} = 2.3 V		8	mA
I _{OL}	Low-level output current	V 2V		16	
		$V_{CC} = 3 V$		24	
		$V_{CC} = 4.5 V$		32	
		$V_{CC} = 1.4 \text{ to } 3V$		20	
Δt/ΔV	Input transition rise or fall	V _{CC} = 3.3 V ± 0.3 V		10	ns/\
	rate	$V_{\rm CC} = 5 \ V \pm 0.5 \ V$		5	
T _A	Operating free-air temperature		-40	85	°C

Note: 4. Unused inputs should be held at Vcc or Ground.





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Electrical Characteristics (All typical values are at Vcc = 3.3V, T_A = 25° C)

Symbol	Parameter	Test Conditions	Vcc	Min	Тур.	Max	Unit	
		I _{OH} = -100µА	1.4 V to 5.5V	$V_{CC} - 0.1$				
		I _{OH} = -3mA	1.4 V	1.05				
		I _{OH} = -4mA	1.65 V	1.2				
V _{OH}	High Level Output Voltage	I _{OH} = -8mA	2.3V	1.9			V	
	Volidge	I _{OH} = -16mA	3 V	2.4]	
		I _{OH} = -24mA	5 V	2.3]	
		I _{OH} = -32mA	4.5 V	3.8				
		I _{OL} = 100μA	1.4 V to 5.5V			0.1		
		I _{OL} = 3mA	1.4V			.4		
		$I_{OL} = 4mA$	1.65 V			0.45		
V _{OL}	High-level Input Voltage	I _{OL} = 8mA	2.3V			0.3	V	
		I _{OL} = 16mA	3 V			0.4		
		$I_{OL} = 24mA$		5 V				0.55
		I _{OL} = 32mA	4.5			0.55		
I _I	Input Current	$V_1 = 5.5 \text{ V or GND}$	0 to 5.5 V			± 5	μA	
I _{OFF}	Power Down Leakage Current	$V_1 \text{ or } V_0 = 5.5 V$	0			± 10	μA	
I _{cc}	Supply Current	$V_1 = 5.5V \text{ of GND}$ $I_0=0$	1.4 V to 5.5V			10	μA	
Ci	Input Capacitance	$V_i = V_{CC} - or GND$	3.3		3.5		pF	
		SOT25	(Note 5)		204			
θ_{JA}	Thermal Resistance Junction-to-Ambient	SOT353	(Note 5)		371		°C/W	
		DFN1410	(Note 5)		430			
		SOT25	(Note 5)		52			
$\theta_{\rm JC}$	Thermal Resistance	SOT353	(Note 5)		143		°C/W	
	Junction-to-Case	DFN1410	(Note 5)		190		-	

Over recommended free-air temperature range (unless otherwise noted)

Note: 5. Test condition for SOT25, SOT353, and DFN1410: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.





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Switching Characteristics

Parameter	From	то	Vcc = ± 0	-		: 1.8 V .15V		= 2.5 V).2V		: 3.3 V .3V	: Vcc ± 0	= 5 V .5V	Unit
	(Input)	(OUTPUT)	Min	Max	Min	Max	Min	Max	Min	Мах	Min	Max	•••••
t _{pd}	A	Y	2	6.4	1.4	4.4	0.8	3.3	0.5	2.7	0.5	2.7	ns

Over recommended free-air temperature range, CL = 30 or 50pF as noted (see Figure 2)

Parameter	From	то	Vcc = ± 0			: 1.8 V .15V		: 2.5 V).2V		: 3.3 V .3V	: Vcc ± 0	= 5 V).5V	Unit
	(Input)	(OUTPUT)	Min	Max	Min	Max	Min	Max	Min	Мах	Min	Мах	
t _{pd}	A	Y	3	7.5	2.1	5.2	1.1	4.1	0.8	3.4	0.9	3.3	ns

Operating Characteristics

T_A = 25 °C

Р	arameter	Test	Vcc = 1.5 V	Vcc = 1.8 V	Vcc = 2.5 V	Vcc = 3.3 V	Vcc = 5 V	Unit
		Conditions	TYP	TYP	TYP	TYP	TYP	
C _{pd}	Power dissipation capacitance	f = 10 MHz	16	16	18	18	20	pF

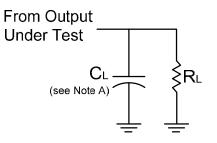




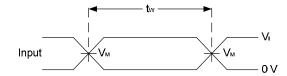
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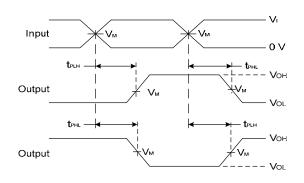
Parameter Measurement Information



Vcc	In	puts	N _e ,	C.	Р.
VCC	VI	t _r /t _f	V _M	CL	RL
1.5V±0.1V	V _{cc}	≤2ns	V _{CC} /2	15pF	1MΩ
1.8V±0.15V	V _{cc}	≤2ns	V _{CC} /2	15pF	1MΩ
2.5V±0.2V	V _{cc}	≤2ns	V _{CC} /2	15pF	1MΩ
3.3V±0.3V	3V	≤2.5ns	1.5V	15pF	1MΩ
5V±0.5V	V _{CC}	≤2.5ns	V _{CC} /2	15pF	1MΩ



Voltage Waveform Pulse Duration



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate ≤ 10 MHz.
- C. Inputs are measured separately one transition per measurement.

D. t_{PLH} and t_{PHL} are the same as $t_{\mathsf{PD.}}$

Figure 1. Load Circuit and Voltage Waveforms

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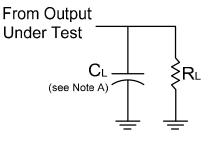




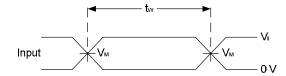
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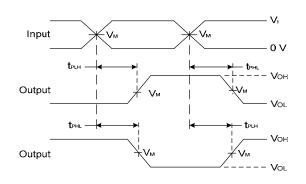
Parameter Measurement Information (Continued)



Vcc	Inp	outs	V _M	CL	RL
	Vi	t _r /t _f	- 141	ΥL	
1.5V±0.1V	V _{cc}	≤2ns	V _{CC} /2	30pF	1KΩ
1.8V±0.15V	V _{CC}	≤2ns	V _{CC} /2	30pF	1KΩ
2.5V±0.2V	V _{cc}	≤2ns	V _{CC} /2	30pF	500Ω
3.3V±0.3V	3V	≤2.5ns	1.5V	50pF	500Ω
5V±0.5V	V _{CC}	≤2.5ns	V _{CC} /2	50pF	500Ω



Voltage Waveform Pulse Duration



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate ≤ 10 MHz.
- C. Inputs are measured separately one transition per measurement.

D. t_{PLH} and t_{PHL} are the same as $t_{\mathsf{PD.}}$

Figure 2. Load Circuit and Voltage Waveforms

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SINGLE INVERTER GATE

-7

-7

-7

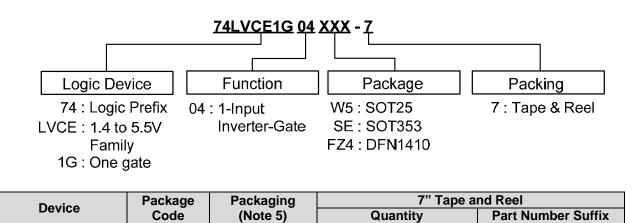
Ordering Information

74LVCE1G04W5-7

74LVCE1G04SE-7

W6

SE



3000/Tape & Reel

3000/Tape & Reel

5000/Tape & Reel 74LVCE1G04FZ4-7 FZ4 **DFN1410** 6. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at Note: http://www.diodes.com/datasheets/ap02001.pdf.

SOT25

SOT353



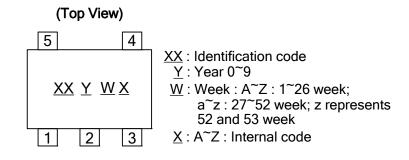


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Marking Information

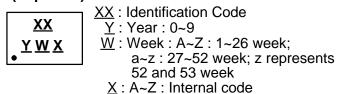
(1) SOT25 and SOT353



Part Number	Package	Identification Code
74LVCE1G04W5	SOT25	PU
74LVCE1G04SE	SOT353	PV

(2) DFN1410H4-6

(Top View)



Part Number	Package	Identification Code
74LVCE1G04FZ4	DFN1410	PU



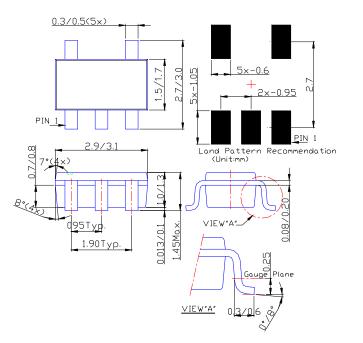


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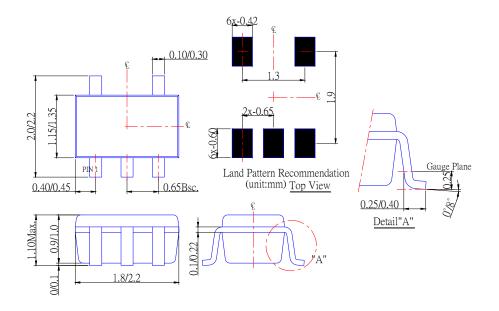
SINGLE INVERTER GATE

Package Outline Dimensions (All Dimensions in mm)

(1) Package Type: SOT25



(2) Package Type: SOT353



NEW PRODUCT



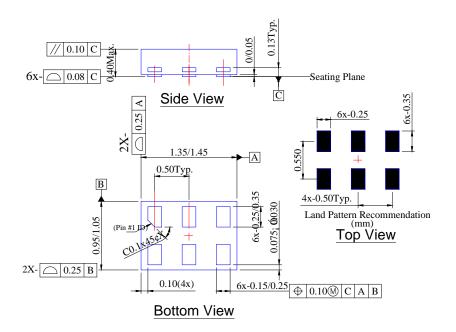


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SINGLE INVERTER GATE

Package Outline Dimensions (All Dimensions in mm)

(3) Package Type: DFN1410





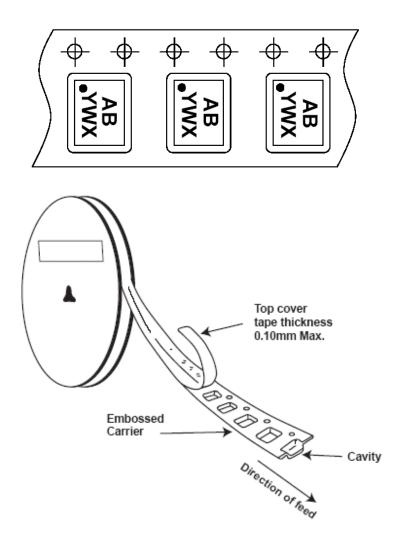


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Taping Orientation (Note 7)

For DFN1410









74LVCE1G04

SINGLE INVERTER GATE

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